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1,2 and 3-Channel ESD Arrays in CSP

Features

- 1, 2 or 3 channels of ESD protection
- ±15kV ESD protection (IEC 61000-4-2, contact discharge)
- ±30kV ESD protection (HBM)
- Supports both AC and DC signal applications
- Low leakage current (<100nA)
- Chip Scale Package features extremely low lead inductance for optimum ESD and filter performance
- 4 bump, 1.06 x 0.93mm footprint Chip Scale Package (CSP)
- Lead-free version available

Applications

- I/O port protection
- · EMI filtering for data ports
- Cellphones, notebook computers, PDAs
- Wireless Handsets
- MP3 Players
- Digital Still Cameras
- Handheld PCs

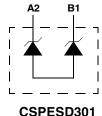
Product Description

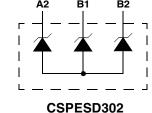
The CSPESD301/302/303 is a family of 1, 2, and 3channel ESD protection arrays, which integrate two, three and four identical avalanche-style diodes. It is intended that one of these diodes is connected to GND and the other diodes provide ESD protection for up to 3 lines depending upon the configuration utilized. The back-to-back diode connections provide ESD protection for nodes that have AC signals up to 5.9V peak. These devices provide a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). The diodes are designed and characterized to safely dissipate ESD strikes of ±15kV, well beyond the maximum requirements of the IEC 61000-4-2 international standard. Using the MIL-STD-883 (Method 3015) specification for Human Body Model (HBM) ESD, these devices protection against contact discharges at greater than ±30kV. The diodes also provide some EMI filtering, when used in combination with a PCB trace or series resistor.

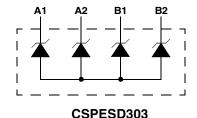
These devices are particularly well suited for portable electronics (e.g. cellular telephones, PDAs, notebook computers) because of their small package format and easy-to-use pin assignments.

The CSPESD301/2/3 is available in a space-saving, low-profile, chip-scale package with optional lead-free finishing.

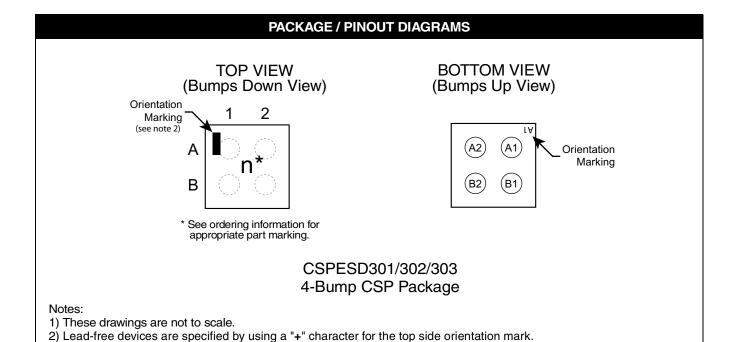
Electrical Schematics











Ordering Information

	PART NUMBERING INFORMATION						
		Standa	rd Finish	Lead-free Finish ²			
Bumps	Package	Ordering Part Number ¹	Part Marking	Ordering Part Number ¹	Part Marking		
4	CSP	CSPESD301	F	CSPESD301G	F		
4	CSP	CSPESD302	G	CSPESD302G	G		
4	CSP	CSPESD303	Н	CSPESD303G	Н		

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

3) All 4 bumps are always present. Unused bumps are electrically unconnected.

Note 2: Lead-free devices are specified by using a "+" character for the top side orientation mark.



Specifications

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	RATING	UNITS				
Storage Temperature Range	-65 to +150	°C				
DC Package Power Rating	200	mW				

STANDARD OPERATING CONDITIONS						
PARAMETER	RATING	UNITS				
Operating Temperature Range	-40 to +85	°C				

ELECTRICAL OPERATING CHARACTERISTICS ¹								
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS		
V _{SO}	Diode Stand-off Voltage	$I_{DIODE} = \pm 10 \mu A$	±5.9			V		
I _{LEAK}	Diode Leakage Current	V _{IN} =3.3V			100	nA		
V _{SIG}	Small Signal Clamp Voltage Positive Clamp Negative Clamp	I _{DIODE} = 10mA I _{DIODE} = -10mA	6.0 -9.2	7.6 -7.6	9.2 -6.0	V V		
V _{ESD}	In-system ESD Withstand Voltage a) Human Body Model, MIL-STD-883, Method 3015 b) Contact Discharge per IEC 61000-4-2	Notes 2, 3 and 4	±30 ±15			kV kV		
V _{CL}	Clamping Voltage during ESD Discharge MIL-STD-883 (Method 3015), 8kV Between adjacent bumps Between diagonal bumps	Notes 2, 3 and 4		19.5 19.9		V V		
R _D	Dynamic Resistance Between adjacent bumps Between diagonal bumps	Notes 2, 3 and 4		0.85 1.10		Ω		
С	Capacitance	At 0VDC, 1MHz, 30mVAC		27		pF		

Note 1: T_A=25°C unless otherwise specified.

Note 2: ESD applied to input and output pins with respect to another diode, one at a time.

Note 3: Unused pins are left open.

Note 4: These parameters are guaranteed by design and characterization.

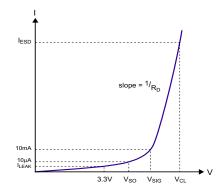


Figure 1. Parameter Legend

Performance Information

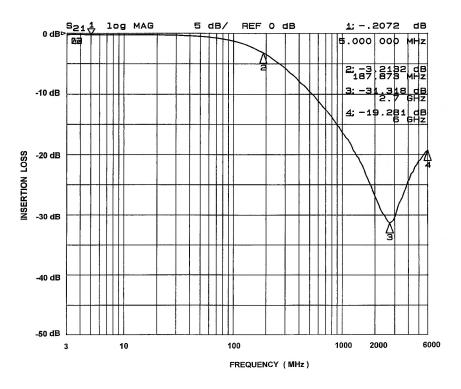


Figure 2. Typical EMI Filter Performance (0VDC, 50 Ohm Environment)

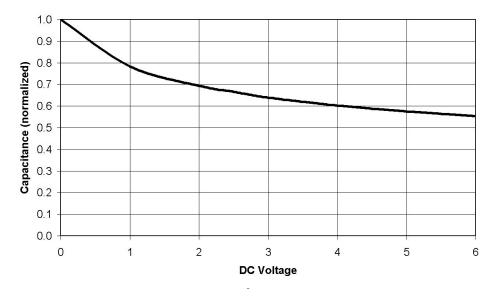


Figure 3. Typical Capacitance VS. Input Voltage (normalized to 0Vdc)

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Performance Information (cont'd)

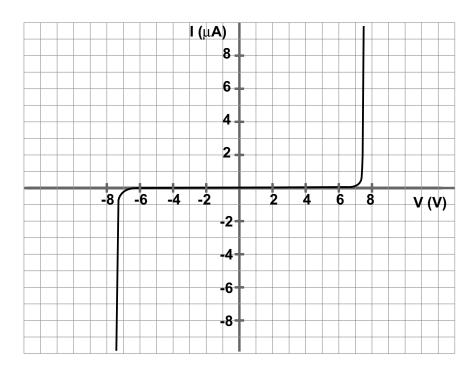


Figure 4. Low Current I-V Curve

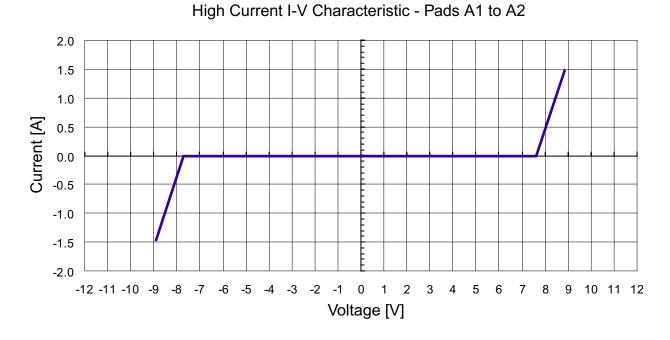


Figure 5. High Current I-V Curve

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Application Information

Refer to Application Note AP-217, "The Chip Scale Package", for a detailed description of Chip Scale Packages offered by California Micro Devices.

PRINTED CIRCUIT BOARD RECOMMENDATIONS						
PARAMETER VALUE						
Pad Size on PCB	0.275mm					
Pad Shape	Round					
Pad Definition	Non-Solder Mask defined pads					
Solder Mask Opening	0.325mm Round					
Solder Stencil Thickness	0.125mm - 0.150mm					
Solder Stencil Aperture Opening (laser cut, 5% tapered walls)	0.330mm Round					
Solder Flux Ratio	50/50 by volume					
Solder Paste Type	No Clean					
Pad Protective Finish	OSP (Entek Cu Plus 106A)					
Tolerance — Edge To Corner Ball	<u>+</u> 50μm					
Solder Ball Side Coplanarity	<u>+</u> 20μm					
Maximum Dwell Time Above Liquidous	60 seconds					
Soldering Maximum Temperature	260°C					

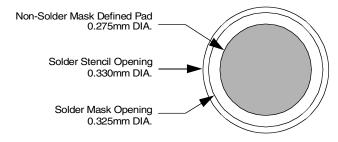


Figure 6. Recommended Non-Solder Mask Defined Pad Illustration

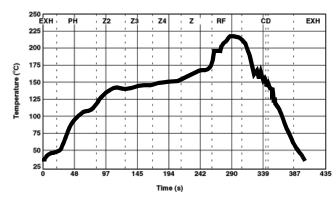


Figure 7. Eutectic (SnPb) Solder **Ball Reflow Profile**

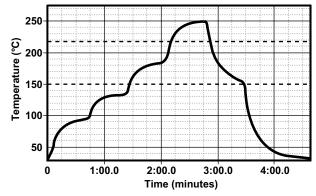


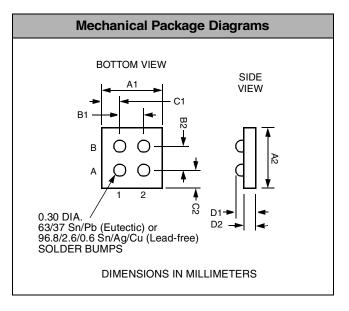
Figure 8. Lead-free (SnAgCu) Solder **Ball Reflow Profile**

Mechanical Details

CSP Mechanical Specifications

CSPESD301/302/303 devices are packaged in a custom Chip Scale Package (CSP). Dimensions are shown below. For complete information on CSP packaging, see the California Micro Devices CSP Package Information document.

PACKAGE DIMENSIONS								
Pack	age	Custom CSP						
Bumps		4						
Dim	M	Millimeters Inches						
Dilli	Min	Nom	Max	Min	Nom	Max		
A1	0.881	0.925	0.971	0.0347	0.0365	0.0382		
A2	1.015	1.060	1.105	0.0400	0.0417	0.0435		
B1	0.495	0.500	0.505	0.0195	0.0197	0.0199		
B2	0.495	0.500 0.505		0.0195	0.0197	0.0199		
C1	0.163	0.213	13 0.263 0.0064 0.00		0.0084	0.0104		
C2	0.230	230 0.280 0.330 0.0091 0.0110 0			0.0130			
D1	0.561	0.605	0.649	0.0221	0.0238	0.0255		
D2	0.355	0.380	0.405	0.0140	0.0150	0.0159		
# per tape and reel		3500 pieces						
Controlling dimension: millimeters								



Package Dimensions for CSPESD301/302/303 Chip Scale Package

CSP Tape and Reel Specifications

PART NUMBER	CHIP SIZE (mm)	POCKET SIZE (mm) B ₀ X A ₀ X K ₀	TAPE WIDTH W	REEL DIAMETER	QTY PER REEL	P ₀	P ₁
CSPESD301 CSPESD302 CSPESD303	1.06 X 0.93 X 0.6	1.14 X 1.00 X 0.70	8mm	178mm (7")	3500	4mm	4mm

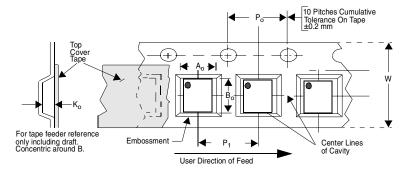


Figure 9. Tape and Reel Mechanical Data